NSN 5962-01-358-9641

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-358-9641
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
350.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and positive outputs and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
60.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
50.0 volts power source
Capitance Rating Per Characteristic:
12.00 input picofarads and 12.00 output picofarads
Time Rating Per Chacteristic:
200.00 nanoseconds delay
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
28 printed circuit
Shelf Life:

N/a

NSN 5962-01-358-9641

Memory Microcircuit - Page 2 of 2



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Demilitarization:

No

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